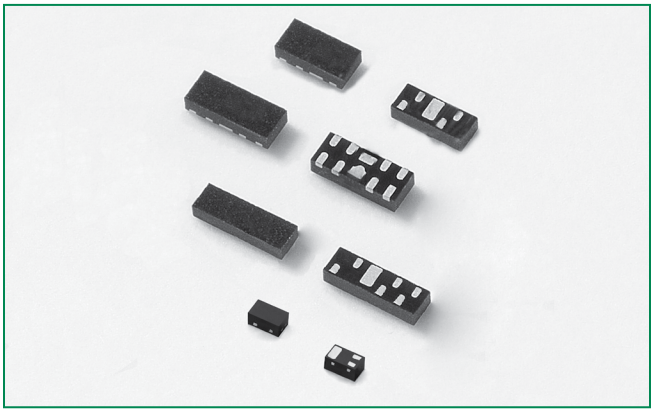
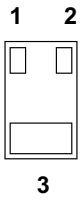
SESD Series Ultra Low Capacitance Diode Arrays

AUTOMOTIVE GRADE | RoHS | Pb | GREEN | ELV

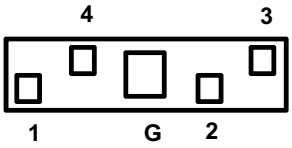


Pinout

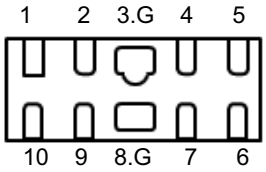
0402 DFN array



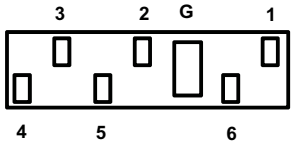
0802 DFN array



1004 DFN array
ACE-Q101 qualified)

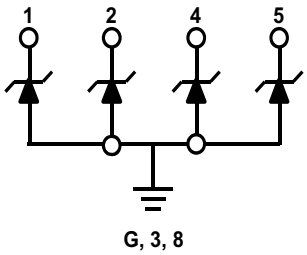


1103 DFN array

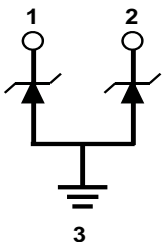


Bottom View

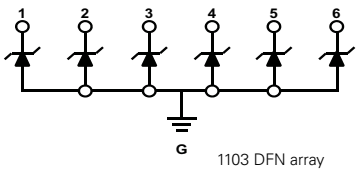
Functional Block Diagram



0802/1004 DFN array



0402 DFN array



1103 DFN array

Description

The SESD series Ultra Low Capacitance Diode Arrays provides signal integrity-preserving unidirectional ESD protection for the world's most challenging high speed serial interfaces. Compelling packaging options including the standard 2.5mmx1.0mm layout, the SOD883, and board space-friendly 0802 and 1103 DFN minimize trace layout complexity, save significant PCB space. Providing in excess of 20kV contact ESD protection (IEC61000-4-2) while maintaining extremely low leakage and dynamic resistance, offered in the industry's most progressive and soon to be popular footprints, the SESD series sets higher standards for signal integrity and usability.

Features

- 0.20pF TYP capacitance
- ESD, IEC61000-4-2, ±20kV contact, ±20kV air
- Low clamping voltage of 9.2V @ I_{PP}=2.0A (t_P=8/20µs)
- Low profile DFN array packages
- Facilitates excellent signal integrity
- AEC-Q101 qualified (1004)
- ELV Compliant
- RoHS Compliant and Lead Free

Applications

- USB 3.1, 3.0, 2.0
- HDMI 2.0, 1.4a, 1.3
- DisplayPort(TM)
- V-by-One®
- Thunderbolt
- LVDS interfaces
- Consumer, mobile and portable electronics
- Tablet PC and external storage with high speed interfaces
- Applications requiring high ESD performance in small packages

Additional Information

Datasheet | **Resources** | **Samples**

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Absolute Maximum Ratings

Symbol	Parameter	Value	Units
I_{PP}	Peak Current (t_p=8/20µs)	2.0	A
T_{OP}	Operating Temperature	-55 to 125	°C
T_{STOR}	Storage Temperature	-55 to 150	°C

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

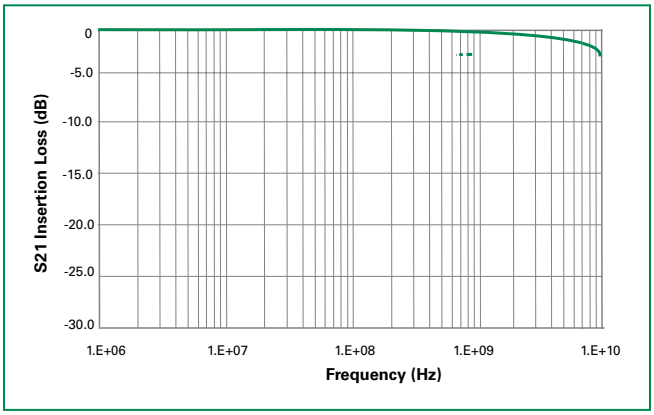
Thermal Information

Parameter	Rating	Units
Storage Temperature Range	-55 to 150	°C
Maximum Junction Temperature	150	°C
Maximum Lead Temperature (Soldering 20-40s)	260	°C

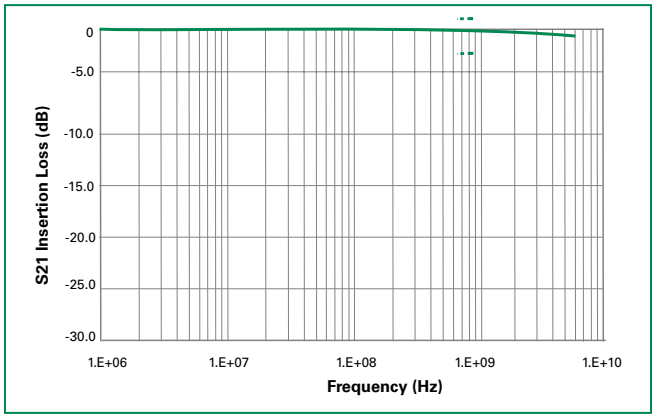
Electrical Characteristics - (T_{OP}=25°C)

Parameter	Test Conditions	Min	Typ	Max	Units
Input Capacitance	@ V_R = 0V, f = 3GHz		0.20	0.22	pF
Breakdown Voltage	V_{BR} @ I_T=1mA		9.00		V
Reverse Working Voltage				7.0	V
Reverse Leakage Current	I_L @ V_{RWM}=5.0V		25	50	nA
Clamping Voltage	V_{CL} @ I_{PP}=2.0A		9.20		V
Peak Pulse Current	t_P=8/20µs			2.0	A
ESD Withstand Voltage	IEC61000-4-2 (Contact)	±20			kV
	IEC61000-4-2 (Air)	±20			

Insertion Loss Diagram

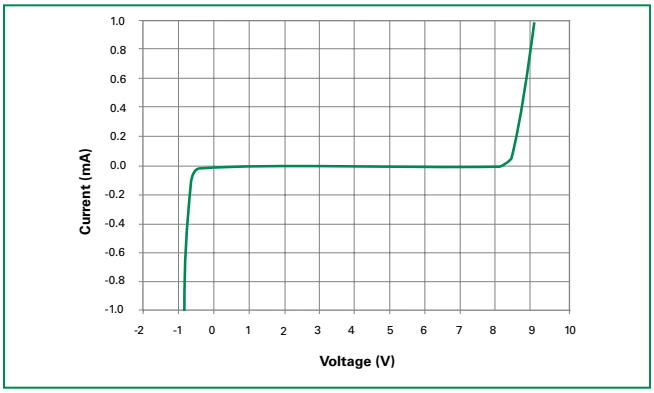


Insertion Loss Diagram - 1103 DFN Array



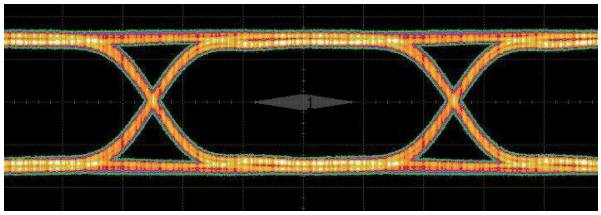
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Device IV Curve

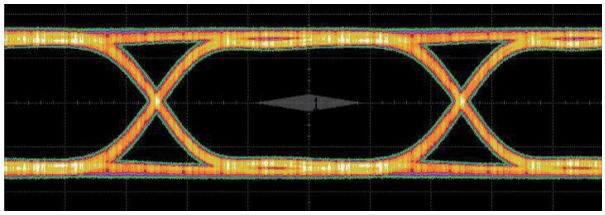


USB3.0 Eye Diagram

5.0 Gb/s, 1000mV differential, CPO Compliant Test Pattern



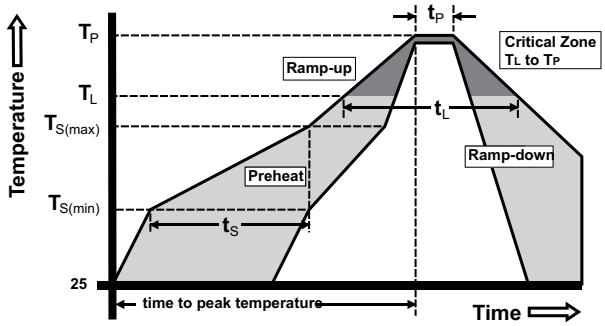
Without SESD Device



With SESD Device

Soldering Parameters

Reflow Condition		Pb – Free assembly
Pre Heat	- Temperature Min ($T_{s(min)}$)	150°C
	- Temperature Max ($T_{s(max)}$)	200°C
	- Time (min to max) (t_s)	60 – 180 secs
Average ramp up rate (Liquidus) Temp (T_L) to peak		3°C/second max
$T_{S(max)}$ to T_L - Ramp-up Rate		3°C/second max
Reflow	- Temperature (T_L) (Liquidus)	217°C
	- Temperature (t_L)	60 – 150 seconds
Peak Temperature (T_P)		$260^{+0/-5}$ °C
Time within 5°C of actual peak Temperature (t_p)		20 – 40 seconds
Ramp-down Rate		6°C/second max
Time 25°C to peak Temperature (T_P)		8 minutes Max.
Do not exceed		260°C



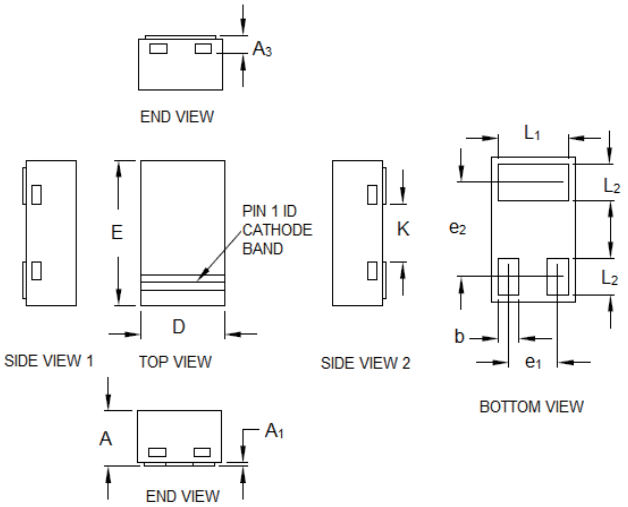
Product Characteristics of 0402 DFN Package

Lead Plating	Pre-Plated Frame
Lead Material	Copper Alloy
Lead Coplanarity	0.0004 inches (0.102mm)
Substrate material	Silicon
Body Material	V-0 per UL 94 Molded Epoxy

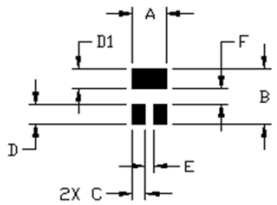
Notes :
1. All dimensions are in millimeters
2. Dimensions include solder plating.
3. Dimensions are exclusive of mold flash & metal burr.
4. Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
5. Package surface matte finish VDI 11-13.

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Package Dimensions — 0402 DFN Array



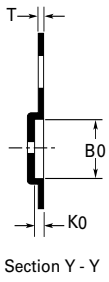
Symbol	Millimeters			Inches		
	Min	Typ	Max	Min	Typ	Max
A	0.33	0.38	0.43	0.013	0.015	0.017
A1	0	-	0.05	0	-	0.002
A3	0.13 ref.			0.005 ref.		
D	0.55	0.60	0.65	0.022	0.024	0.026
E	0.95	1.00	1.05	0.037	0.039	0.041
K	0.35	0.40	0.45	0.014	0.016	0.018
L1	0.45	0.50	0.55	0.018	0.020	0.022
L2	0.20	0.25	0.30	0.008	0.010	0.012
b	0.10	0.15	0.20	0.004	0.006	0.008
e1	0.35 BSC			0.014 BSC		
e2	0.65 BSC			0.026 BSC		



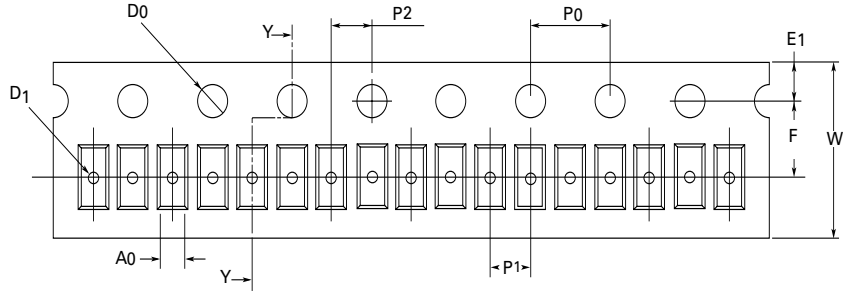
Pad Layout

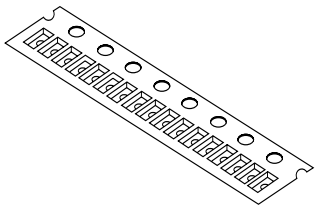
Symbol	Millimeters	Inches
A	0.60	0.024
B	1.00	0.039
C	0.23	0.009
D	0.35	0.014
D1	0.35	0.014
E	0.15	0.006
F	0.30	0.012

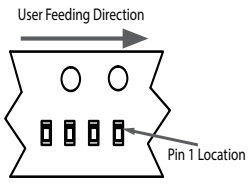
Embossed Carrier Tape & Reel Specification — 0402 DFN Array



Section Y - Y



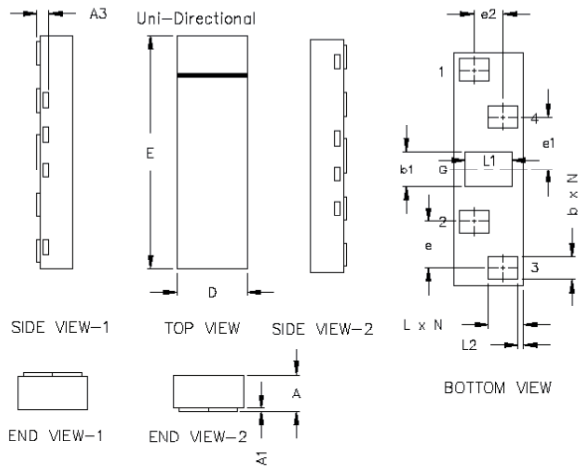




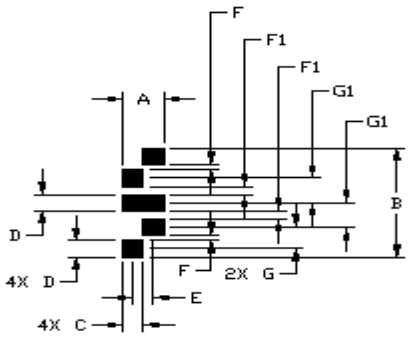
Symbol	Millimeters
A0	0.70+/-0.05
B0	1.15+/-0.05
D0	ø 1.55 + 0.05
D1	ø 0.40 +/- 0.05
E1	1.75+/-0.10
F	3.50+/-0.05
K0	0.47+/-0.05
P0	4.00+/-0.10
P1	2.00+/-0.05
P2	2.00+/-0.05
W	8.00 +/-0.10
T	0.20+/-0.05

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Package Dimensions — 0802 DFN Array



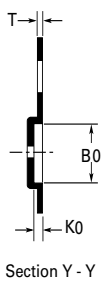
Symbol	Millimeters			Inches		
	Min	Typ	Max	Min	Typ	Max
A	0.33	0.38	0.43	0.013	0.015	0.017
A1	0	0.02	0.05	0	--	0.002
A3		0.127 ref			0.005 ref.	
D	0.50	0.60	0.70	0.020	0.024	0.028
E	1.90	2.00	2.10	0.075	0.079	0.083
b	0.15	0.20	0.25	0.006	0.008	0.010
b1	0.25	0.30	0.36	0.010	0.012	0.014
L	0.25	0.30	0.36	0.010	0.012	0.014
L1	0.35	0.40	0.45	0.014	0.016	0.018
L2		0.05 BSC			0.002 BSC	
e		0.40 BSC			0.016 BSC	
e1		0.45 BSC			0.018 BSC	
e2		0.25 BSC			0.010 BSC	
N		4			4	

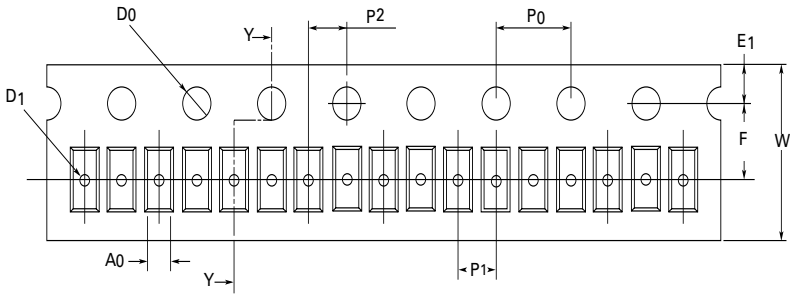


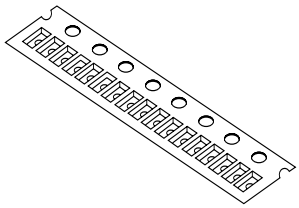
Pad Layout

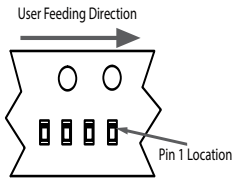
Symbol	Millimeters	Inches
A	0.60	0.024
B	2.00	0.079
C	0.30	0.012
D	0.30	0.012
E	0.30	0.012
F	0.10	0.004
F1	0.15	0.006
G	0.40 BSC	0.016 BSC
G1	0.45 BSC	0.018 BSC

Embossed Carrier Tape & Reel Specification — 0802 DFN Array





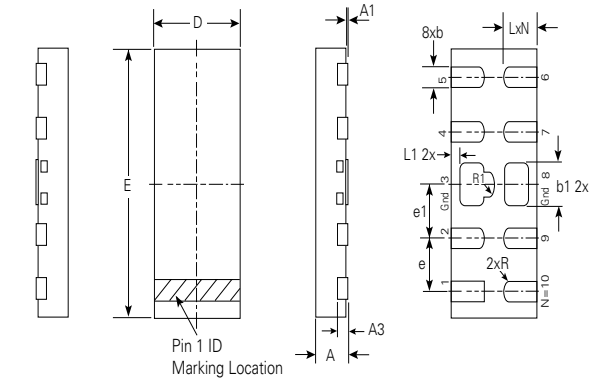




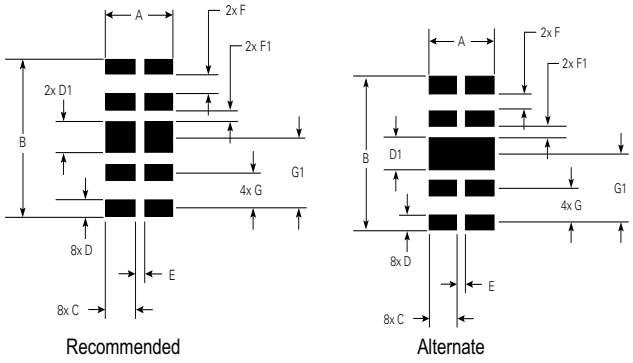
Symbol	Millimeters
A0	0.81+/-0.05
B0	2.21+/-0.05
D0	ø 1.50+0.10/-0
D1	ø 0.40 min
E1	1.75+/-0.10
F	3.50+/-0.05
K0	0.46+/-0.05
P0	4.00+/-0.10
P1	2.00+/-0.10
P2	2.00+/-0.05
W	8.00+0.30/-0.10
T	0.25+/-0.20

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Package Dimensions — 1004 DFN Array





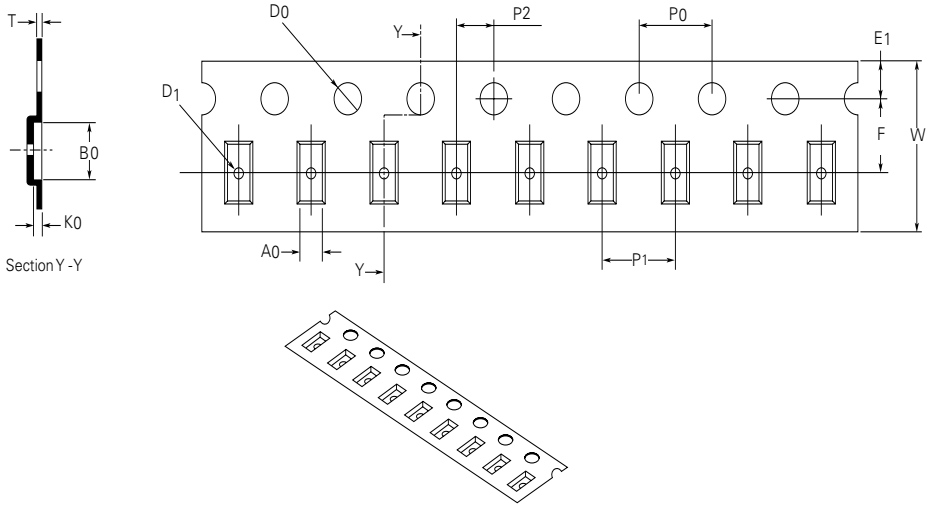


Symbol	Millimeters			Inches		
	Min	Typ	Max	Min	Typ	Max
A	0.33	0.38	0.43	0.013	0.015	0.017
A1	0.00	0.02	0.05	0	--	0.002
A3	0.127 ref.			0.005 ref.		
D	0.90	1.00	1.10	0.035	0.039	0.043
E	2.40	2.50	2.60	0.094	0.098	0.102
b	0.15	0.20	0.25	0.006	0.008	0.010
b1	0.35	0.40	0.45	0.014	0.016	0.018
L	0.33	0.38	0.43	0.013	0.015	0.017
L1	0.00	0.10	0.15	0.000	0.004	0.006
e	0.50 BSC			0.020 BSC		
e1	0.50 BSC			0.020 BSC		
R	0.08 BSC			0.003 BSC		
R1	0.13 BSC			0.005 BSC		
N	10			10		

Symbol	Millimeters	Inches
A	1.20	0.047
B	2.20	0.087
C	0.50	0.020
D	0.20	0.008
D1	0.40	0.016
E	0.20	0.008
F	0.30	0.012
F1	0.20	0.008
G	0.50 BSC	0.020 BSC
G1	1.00 BSC	0.039 BSC

Pad Layout

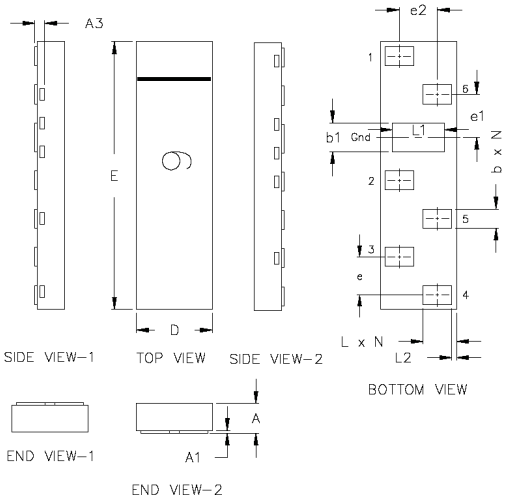
Embossed Carrier Tape & Reel Specification — 1004 DFN Array



Symbol	Millimeters
A0	1.20+/-0.05
B0	2.70+/-0.05
D0	ø 1.50+0.10/-0
D1	ø 0.50 min
E1	1.75+/-0.10
F	3.50+/-0.05
K0	0.51+/-0.10
P0	4.00+/-0.10
P1	4.00+/-0.10
P2	2.00+/-0.05
W	8.00+0.30/-0.10
T	0.25+/-0.05

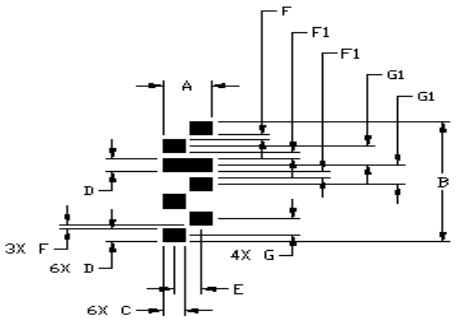
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Package Dimensions — 1103 DFN Array



Symbol	Millimeters			Inches		
	Min	Typ	Max	Min	Typ	Max
A	0.33	0.38	0.43	0.013	0.015	0.017
A1	0.00	0.02	0.05	0	--	0.002
A3		0.127 ref.			0.005 ref.	
D	0.70	0.80	0.90	0.027	0.031	0.035
E	2.70	2.80	2.90	0.106	0.110	0.114
b	0.15	0.20	0.25	0.006	0.008	0.010
b1	0.25	0.30	0.35	0.010	0.012	0.014
L	0.30	0.35	0.40	0.012	0.014	0.016
L1	0.50	0.55	0.60	0.019	0.021	0.024
L2		0.05 BSC			0.002 BSC	
e		0.40 BSC			0.016 BSC	
e1		0.45 BSC			0.018 BSC	
e2		0.40 BSC			0.016 BSC	
N		6			6	

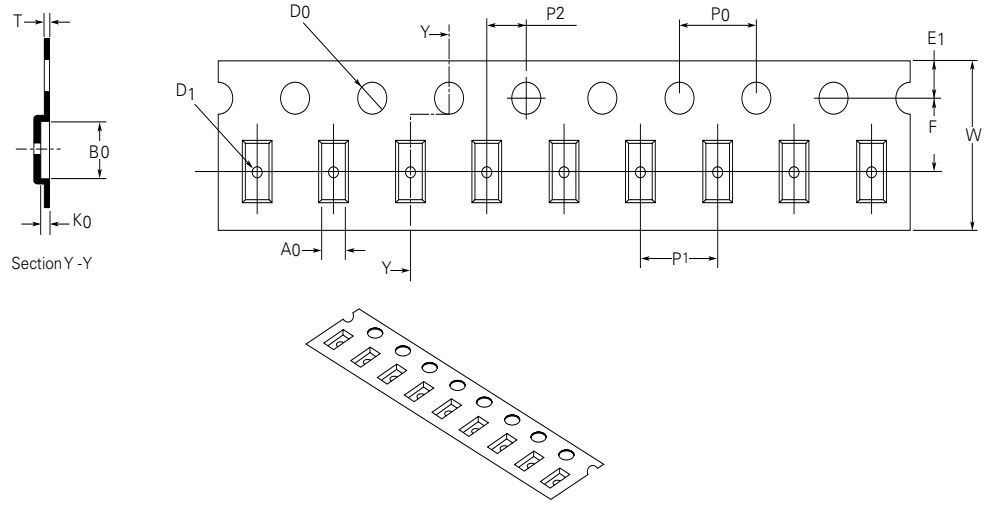
4



Pad Layout

Symbol	Millimeters	Inches
A	0.80	0.031
B	2.80	0.110
C	0.35	0.014
D	0.30	0.012
E	0.45	0.018
F	0.10	0.004
F1	0.15	0.006
G	0.40 BSC	0.016 BSC
G1	0.45 BSC	0.018 BSC

Embossed Carrier Tape & Reel Specification — 1103 DFN Array



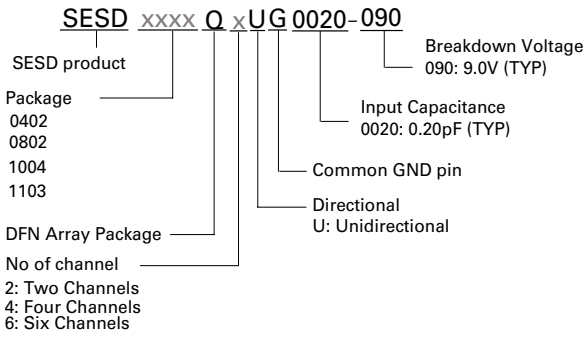
Symbol	Millimeters
A0	1.00+/-0.05
B0	3.00+/-0.05
D0	ø 1.50+0.10/-0
D1	ø 0.50 min
E1	1.75+/-0.10
F	3.50+/-0.05
K0	0.51+/-0.05
P0	4.00+/-0.10
P1	4.00+/-0.10
P2	2.00+/-0.05
W	8.00+0.30/-0.10
T	0.25+/-0.05

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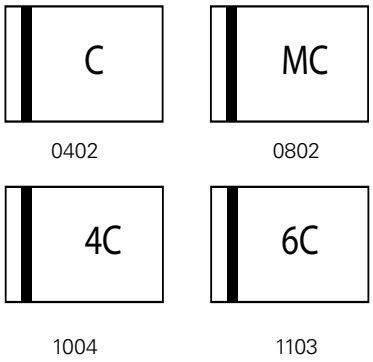
TVS Diode Arrays (SPA® Diodes)

SESD Series Ultra Low Capacitance Diode Arrays

Part Numbering System



Part Marking System



Ordering Information

Part Number	Package	Marking	Ordering Part Number	Minimum Order Quantity
SESD0402Q2UG-0020-090	0402 DFN Array	I C	RF2946-000	50,000
SESD0802Q4UG-0020-090	0802 DFN Array	I MC	RF3076-000	25,000
SESD1004Q4UG-0020-090	1004 DFN Array	I 4C	RF3077-000	25,000
SESD1103Q6UG-0020-090	1103 DFN Array	I 6C	RF3078-000	25,000

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